TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

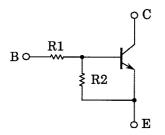
# RN1967, RN1968, RN1969

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

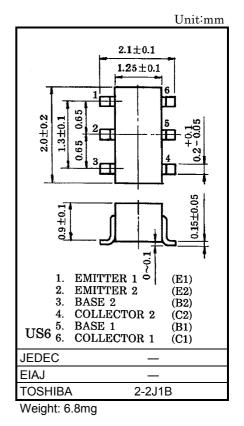
- Including two devices in US6 (ultra super mini type 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2967~RN2969

### **Equivalent Circuit and Bias Resistor Values**

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

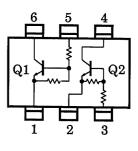


Type No.	R1 (kΩ)	R2 (kΩ)			
RN1967	10	47			
RN1968	22	47			
RN1969	47	22			



### Equivalent Circuit (Top View)

Characteristic	Symbol	Rating	Unit		
Collector-base voltage	RN1967~1969	V <sub>CBO</sub>	50	V	
Collector-emitter voltage	RN1967~1969	V <sub>CEO</sub>	50	V	
	RN1967		6	v	
Emitter-base voltage	RN1968	V <sub>EBO</sub>	7		
	RN1969		15		
Collector current	RN1967~1969	Ι <sub>C</sub>	100	mA	
Collector power dissipation	RN1967~1969	P <sub>C</sub> *	200	mW	
Junction temperature RN1967~1		Tj	150	°C	
Storage temperature range RN1967~1969		T <sub>stg</sub>	-55~150	°C	



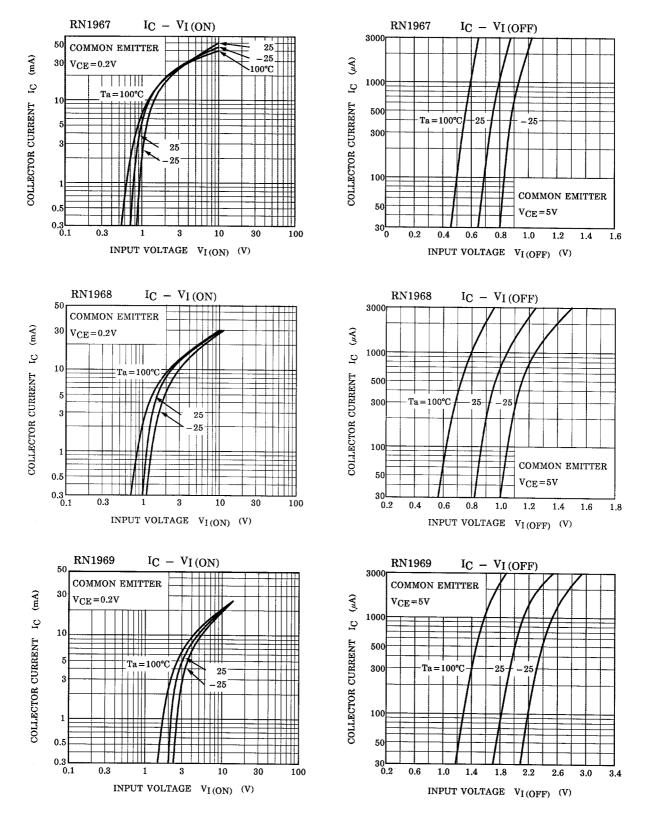
\*: Total rating

### Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1967~1969	I <sub>CBO</sub>	—	$V_{CB} = 50V, I_E = 0$	-	—	100	nA
Collector cut-on current	KN 1907~1909	ICEO	_	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	_	_	500	nA
	RN1967		_	V <sub>EB</sub> = 6V, I <sub>C</sub> = 0	0.081	_	0.15	
Emitter cut-off current	RN1968	I <sub>EBO</sub>	_	V <sub>EB</sub> = 7V, I <sub>C</sub> = 0	0.078	_	0.145	mA
	RN1969		_	V <sub>EB</sub> = 15V, I <sub>C</sub> = 0	0.167	_	0.311	
	RN1967	hFE	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	80	_	_	
DC current gain	RN1968		_		80	_	_	
	RN1969		_		70	_	_	
Collector-emitter saturation voltage	RN1967~1969	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
	RN1967	V <sub>I (ON)</sub>	_	V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	0.7	_	1.8	V
Input voltage (ON)	RN1968		_		1.0	_	2.6	
	RN1969		_		2.2	_	5.8	
	RN1967	V <sub>I (OFF)</sub>	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	0.5	_	1.0	v
Input voltage (OFF)	RN1968		_		0.6	_	1.16	
	RN1969		_		1.5	_	2.6	
Translation frequency	RN1967~1969	f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector output capacitance	RN1967~1969	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0 f = 1MHz	_	3	6	pF
	RN1967	1968 R1	_		7	10	13	kΩ
Input resistor	RN1968		_		15.4	22	28.6	
	RN1969				32.9	47	61.1	
	RN1967	R1/R2	—		0.191	0.213	0.232	_
Resistor ratio	RN1968		_		0.421	0.468	0.515	
	RN1969		_		1.92	2.14	2.35	

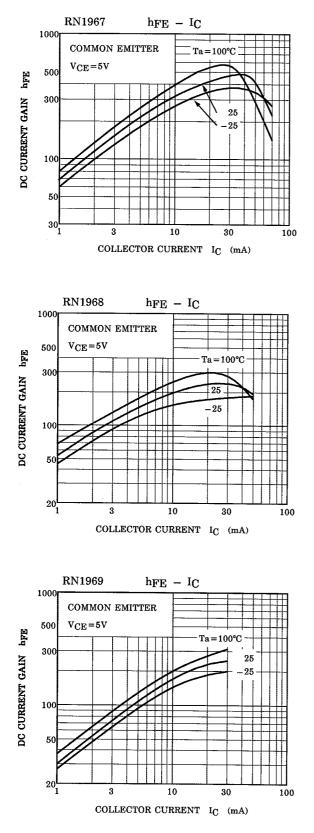
### TOSHIBA

#### (Q1, Q2 Common)



## **TOSHIBA**

#### (Q1, Q2 Common)



Type Name	Marking
RN1967	Type Name XXH
RN1968	Type Name XXI EEE
RN1969	Type Name XXJ BBB

### **RESTRICTIONS ON PRODUCT USE**

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.